





# Exploring topological effects and frustration in different Artificial Spin Ice geometries

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Artificial spin ices (ASIs) are examples of magnetic interacting nanostructures which have opened a way to study topological phenomena such as frustration, emergent magnetic monopoles and phase transitions. Geometric properties of the ASI are key to determine the dynamics of the magnetic charges and the possible energetic configurations, which can also have an influence on the magnetic textures present in these systems. The main goal of this work is to characterize the magnetic properties, spin textures and frustration in ASIs with different geometries and its influence in the formation and ordering of magnetic features. Different geometries of ASI systems had been fabricated by combining nanolithography techniques (optical and electronic lithography) and DC magnetron sputtering. Nanostructures were characterized using different microscopy techniques, magnetic force microscopy (MFM), magnetotransport and micromagnetic simulations.







The distance between magnetics charges is variable but we still see topology

4 macrospins instead of 3 Now it is a Spin Ice (no pseudo spin ice like the 3 previous geometries)

## **Next Steps**

- **Given Studying magnetotransport at different temperatures and in different geometries.**
- **Exploring the Planar Hall effect in ASIs.**
- Enhancing our understanding of the irreversible magnetization process in the system and improving simulations

#### References

[1]Nisoli, C. et al.Rev. of Modern Physics 85 (2013)
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